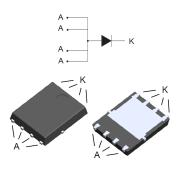




Datasheet

60 V, 30 A high efficiency PowerFLAT power Schottky diode





PowerFLAT 5 x 6 (non-contractual)

Features

- Low forward voltage drop
- Very low conduction losses
- Low thermal resistance
- Avalanche rated
- High integration
- Thin package: 1 mm
- ECOPACK2 compliant

Applications

- Switching diode
- SMPS
- DC/DC converter
- Telecom power

Description

This Schottky rectifier is ideally suited for switch mode power supply and high frequency DC to DC converters.

Packaged in PowerFLAT 5x6, the STPS30M60DJF is optimized for use in low voltage high frequency inverters, free-wheeling and polarity protection applications. Its low profile was especially designed to be used in applications with space-saving constraints.

Product status link STPS30M60DJF

Product summary			
Symbol Value			
I _{F(AV)}	30 A		
V _{RRM}	60 V		
T _j (max.) 150 °C			
V _F (typ.) 0.46 ∨			



1 Characteristics

Table 1. Absolute ratings (limiting values at 25 °C, unless otherwise specified, anode terminals shortcircuited)

Symbol	Parameter	Value	Unit	
V _{RRM}	Repetitive peak reverse voltage	60	V	
I _{F(RMS)}	Forward rms current	45	А	
I _{F(AV)}	Average forward current, δ = 0.5 square wave	T _c = 100 °C	30	А
I _{FSM}	Surge non repetitive forward current	t _p = 10 ms sinusoidal	250	А
P _{ARM}	Repetitive peak avalanche power $t_p = 10 \ \mu s, T_j = 125 \ ^{\circ}C$		1370	W
T _{stg}	Storage temperature range	-65 to +175	°C	
Тj	Maximum operating junction temperature ⁽¹⁾	+150	°C	

1. $(dP_{tot}/dT_j) < (1/R_{th(j-a)})$ condition to avoid thermal runaway for a diode on its own heatsink.

Table 2. Thermal resistance parameters

Symbol	Parameter	Max.	Unit
R _{th(j-c)}	Junction to case	2	°C/W

For more information, please refer to the following application note:

AN5046: Printed circuit board assembly recommendations for STMicroelectronics PowerFLAT packages

Table 3. Static electrical characteristics (anode terminals short-circuited)

Symbol	Parameter	Test conditions		Min.	Тур.	Max.	Unit
	Poverso loskago surrent	T _j = 25 °C	V_ = V	-		90	μA
'R` '	I _R ⁽¹⁾ Reverse leakage current	T _j = 125 °C	V _R = V _{RRM}	-	20	50	mA
		T _j = 25 °C	I _F = 15 A	-		0.59	V
V _F ⁽²⁾	Forward valtage drag	T _j = 125 °C		-	0.46	0.52	
VF Polward Voltage drop	Forward voltage drop	T _j = 25 °C	I _F = 30 A	-		0.72	V
		T _j = 125 °C		-	0.57	0.67	

1. Pulse test: $t_p = 5 ms$, $\delta < 2\%$

2. Pulse test: $t_p = 380 \ \mu s, \ \delta < 2\%$.

To evaluate the conduction losses, use the following equation:

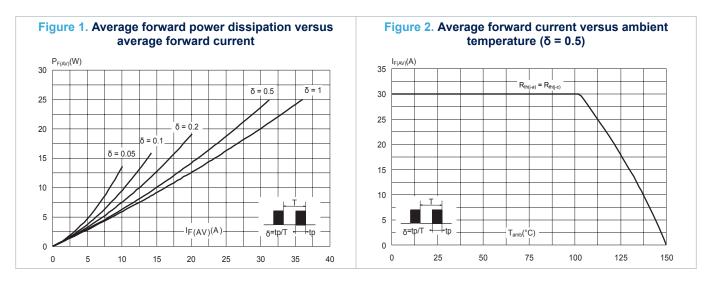
 $P = 0.55 \text{ x } I_{F(AV)} + 0.004 \text{ x } I_{F}^{2}(RMS)$

For more information, please refer to the following application notes related to the power losses:

- AN604: Calculation of conduction losses in a power rectifier
- AN4021: Calculation of reverse losses in a power diode



1.1 Characteristics (curves)





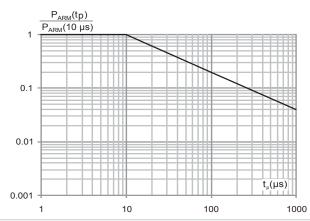
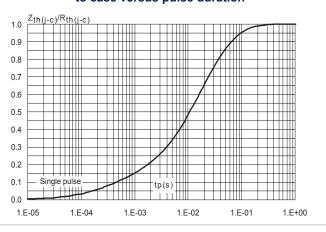


Figure 4. Relative variation of thermal impedance junction to case versus pulse duration



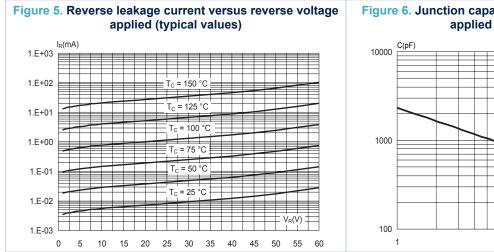
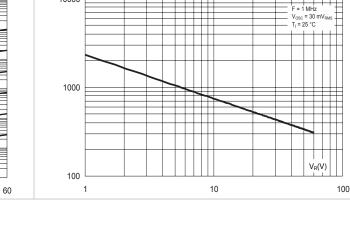


Figure 6. Junction capacitance versus reverse voltage applied (typical values)





STPS30M60DJF Characteristics (curves)

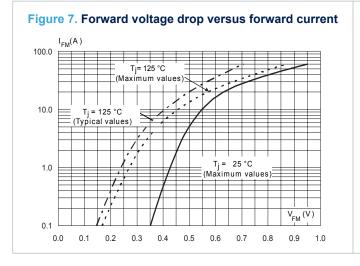
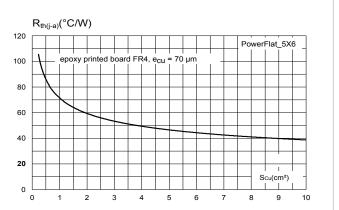


Figure 8. Thermal resistance junction to ambient versus copper surface under tab (typical values)





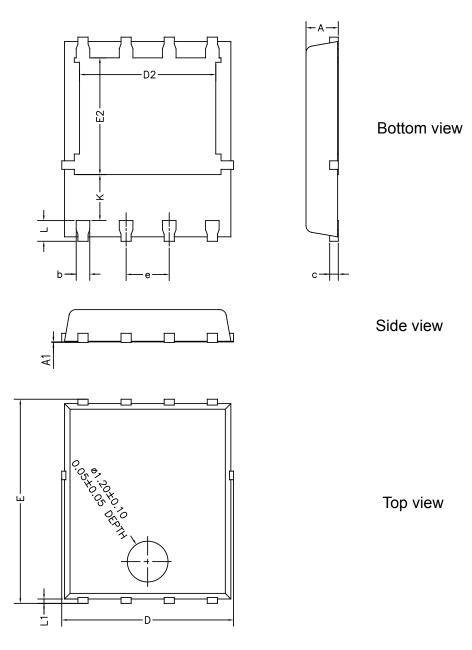
2 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK packages, depending on their level of environmental compliance. ECOPACK specifications, grade definitions and product status are available at: www.st.com. ECOPACK is an ST trademark.

2.1 PowerFLAT 5x6 package information

- Epoxy meets UL 94,V0
- Cooling method: by conduction (C)

Figure 9. PowerFLAT 5x6 package outline (non-contractual)

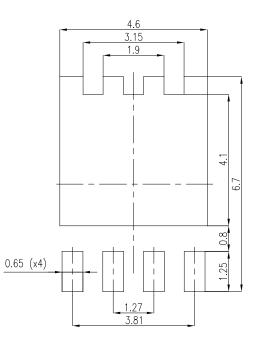


Note: This package drawing may slightly differ from the physical package. However, all the specified dimensions are guaranteed.

Dimensions							
		Millimeters			Inches (for reference only)		
Ref	Min.	Тур.	Max.	Min.	Тур.	Max.	
А	0.80		1.00	0.031		0.039	
A1	0.00		0.05	0.000		0.002	
b	0.30		0.50	0.01		0.02	
С		0.25			0.010		
D	4.80		5.40	0.189		0.212	
D2	3.91		4.45	0.154		0.175	
е		1.27			0.050		
Е	5.90		6.35	0.232		0.250	
E2	3.34		3.70	0.138		0.146	
L	0.50		0.80	0.020		0.031	
К	1.10		1.575	0.015		0.023	
L1	0.05	0.15	0.25	0.002	0.006	0.009	

Table 4. PowerFLAT 5x6 mechanical data

Figure 10. PowerFLAT 5x6 recommended footprint (dimensions are in mm)



Note: For packing information, please refer to TN1173.



3 Ordering information

Table 5. Ordering information

Order code	Marking	Package	Weight	Base qty.	Delivery mode
STPS30M60DJF-TR	PS30 M60	PowerFLAT 5x6	0.095 g	3000	Tape and reel

Revision history

Table 6. Document revision history

Date	Revision	Changes
18-Apr-2012	1	First issue.
15-Mar-2023	2	Updated cover image, Figure 8. Thermal resistance junction to ambient versus copper surface under tab (typical values) and Section 2.1 PowerFLAT 5x6 package information.Added Section Applications.

STPS30M60DJF

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